

MJE13006/13007

High Voltage Switch Mode Application

- High Speed Switching
- Suitable for Switching Regulator and Motor Control



1.Base 2.Collector 3.Emitter

NPN Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	W.	Value	Units
V _{CBO}	Collector-Base Voltage	: MJE13006	600	V
	EP 3 0750.0	: MJE13007	700	V
V _{CEO}	Collector-Emitter Voltage	: MJE13006	300	V
	The same of the sa	: MJE13007	400	V
V _{EBO}	Emitter- Base Voltage		9	V
Ic	Collector Current (DC)		8	Α
I _{CP}	Collector Current (Pulse)		16	A
I _B	Base Current		4	Α
P _C	Collector Dissipation (T _C =25°C)		80	W
T _J	Junction Temperature	1900	150	°C
T _{STG}	Storage Temperature	01//0	- 65 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector- Emitter Breakdown Voltage : MJE13006 : MJE13007	I _C = 10mA, I _B = 0	300 400			V V
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$	- 10		1	mA
h _{FE}	*DC Current Gain	$V_{CE} = 5V, I_{C} = 2A$ $V_{CE} = 5V, I_{C} = 5A$	8 5		60 30	C-60
V _{CE} (sat)	*Collector-Emitter Saturation Voltage	$I_C = 2A, I_B = 0.4A$ $I_C = 5A, I_B = 1A$ $I_C = 8A, I_B = 2A$		M	1 2 3	V V V
V _{BE} (sat)	*Base-Emitter Saturation Voltage	$I_C = 2A$, $I_B = 0.4A$ $I_C = 5A$, $I_B = 1A$			1.2 1.6	V
C _{ob}	Output Capacitance	V _{CB} = 10V, f = 0.1MHz		110		pF
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.5A$	4			MHz
t _{ON}	Turn ON Time	$V_{CC} = 125V, I_{C} = 5A$			1.6	μs
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = 1A$			3	μs
t _F	Fall Time	$R_L = 50\Omega$			0.7	μs

^{*} Pulse test: PW≤300μs, Duty cycle≤2%

Typical Characteristics

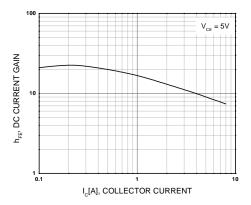


Figure 1. DC current Gain

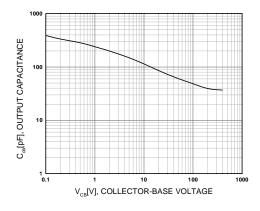


Figure 3. Collector Output Capacitance

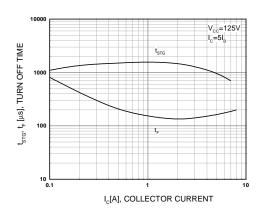


Figure 5. Turn Off Time

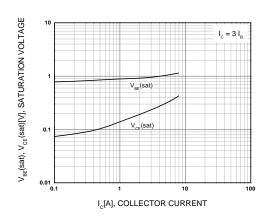


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

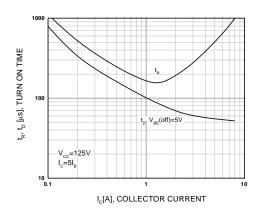


Figure 4. Turn On Time

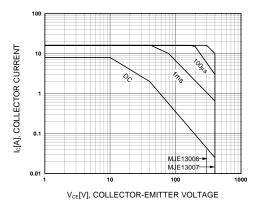


Figure 6. Safe Operating Area

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Typical Characteristics (Continued)

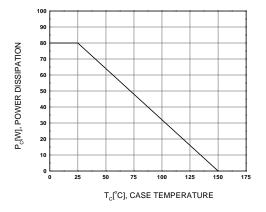
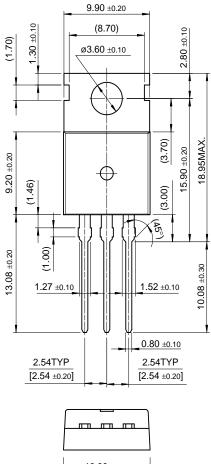
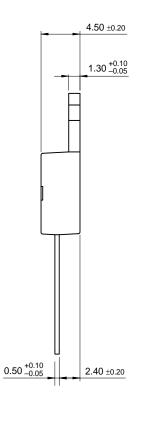


Figure 7. Power Derating

Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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